

# Thermal Management Concepts

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Minnowbrook 06  
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# *Two approaches*

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- Removing heat
  - Dense electronics
  - High performance ICs
  - Detectors
- Preventing the transport of heat (insulation)
  - Hypersonic flight
  - Microcoolers
  - Sensors
  - Detectors



# *Team members*

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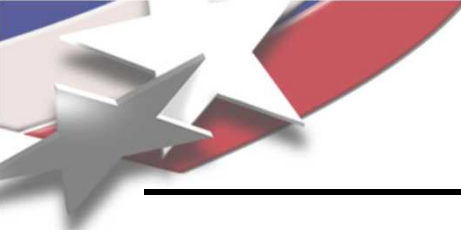
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- **Demand for more speed and capability**
- **Electronic and electro-optical elements**
- **Ever greater chip densities**
- **Conventional heat removal technologies**
  - **Convection (moving air)**
  - **Liquid (circulating, spray, and immersion)**
  - **Conduction (solid materials)**

- **Product lines are dropped**
- **Multicore microprocessors**
  - Two and quad cores
- **Optical communications**
  - Active components can be separated
- **High performance functionally delayed**
  - Teraflop in a “coke can”



# Conduction in solids

**Simple metals – electrons**

**Non metals – thermal vibrations (phonons)**

**Alloys and semiconductors – combination**

	Thermal conductivity, (W/m·K)
Diamond	2000-2500
Silver	429
Copper	401
Silicon	149
Polystyrene	.033
Air (200 kPa)	.026

# Feel the heat

**Smaller chip  
dimensions, larger  
current leakage**

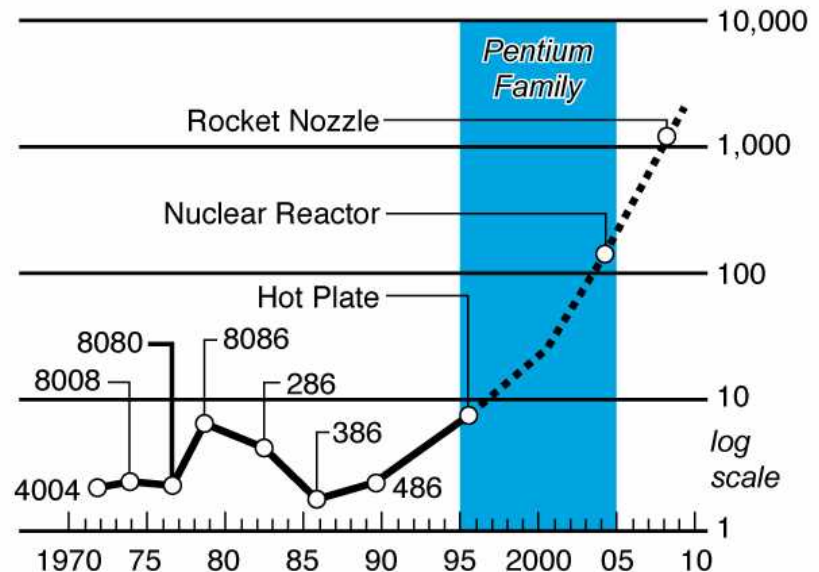
**Electronic assemblies  
become more compact**

**Escalating heat fluxes  
have become difficult  
to manage**

**Efficient heat transfer  
is necessary to  
dissipate heat**

## Hotting up

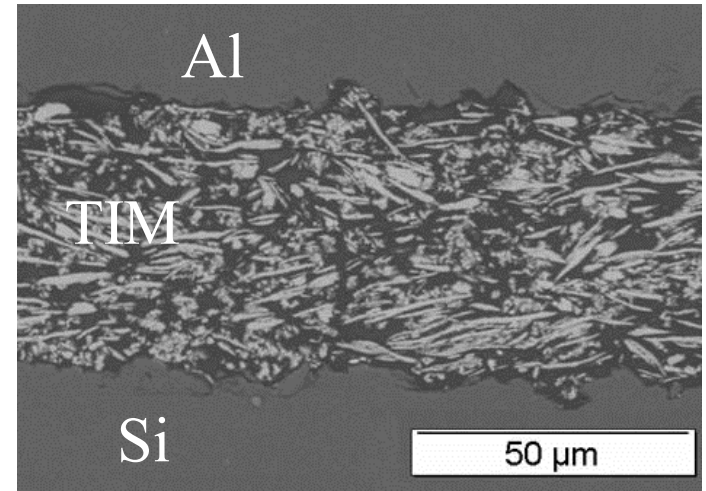
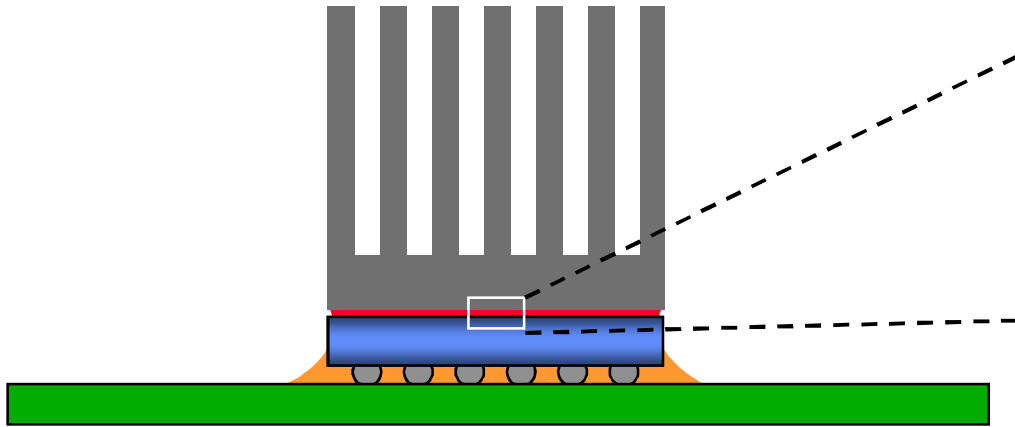
Heat generated by Intel processors  
Power density, watts/sq.cm



Source: Intel

[**Economist, 2003**]

# Thermal bondline



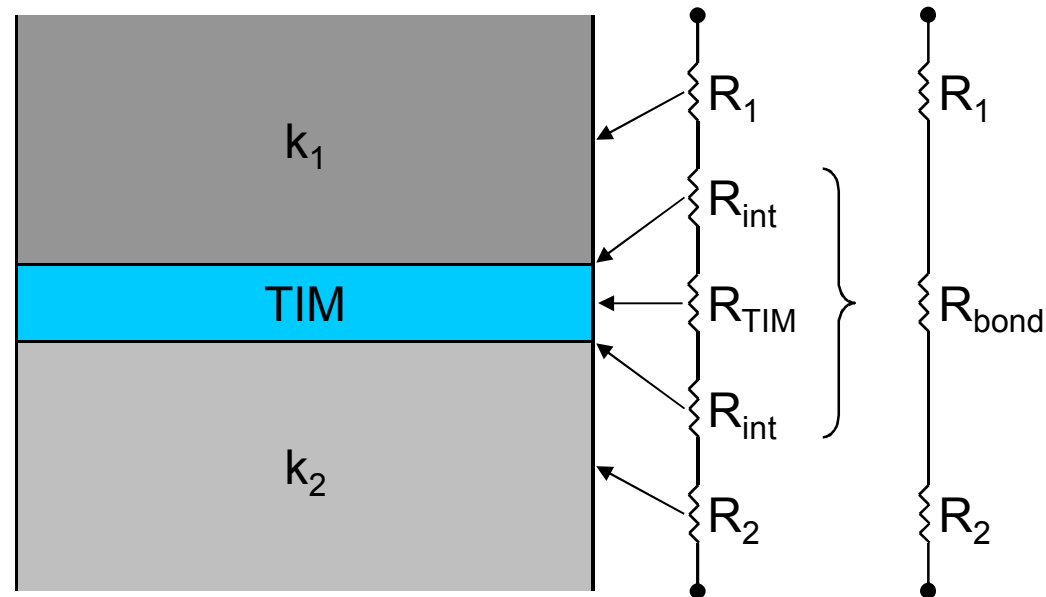
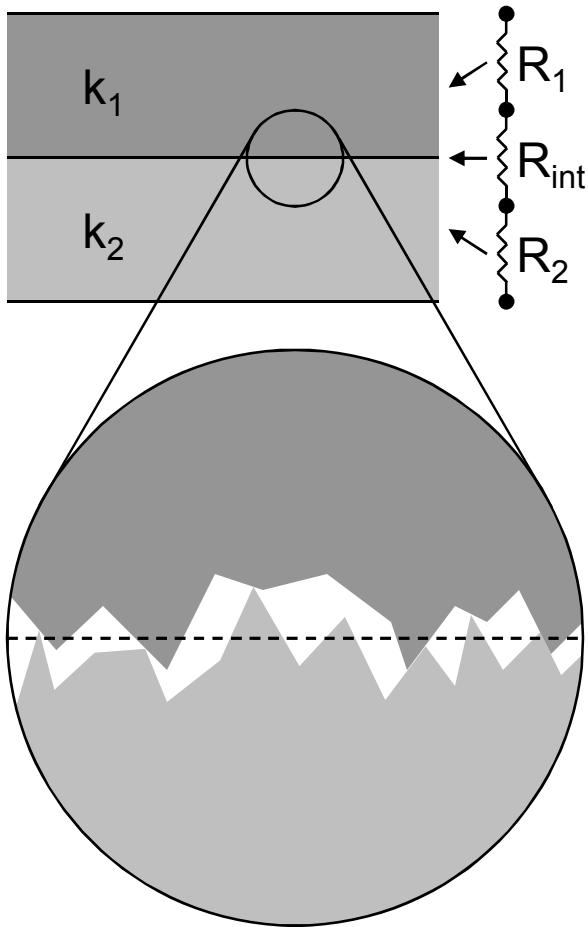
## Deviation from theoretical $R_{\text{bondline}}$

- Phonon scattering at the interfaces
- Incomplete wetting
- Voiding or delamination
- Processing induced heterogeneity



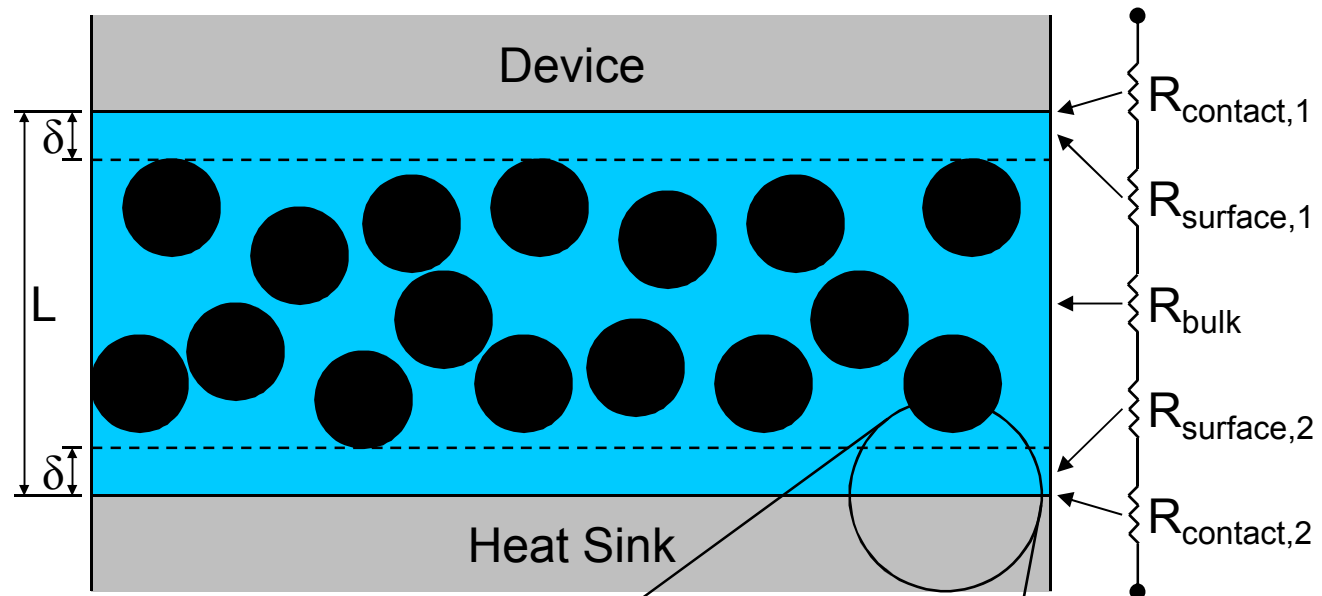
# Thermal Interface Materials

**TIMs reduce the overall thermal resistance between a device and a heat sink by filling the gap between them**



$$R_{bond} = R_{int} + R_{TIM} + R_{int} =$$
$$2R_{int} + L / k_{TIM} = \frac{(\Delta T)_{TIM}}{q_y}$$

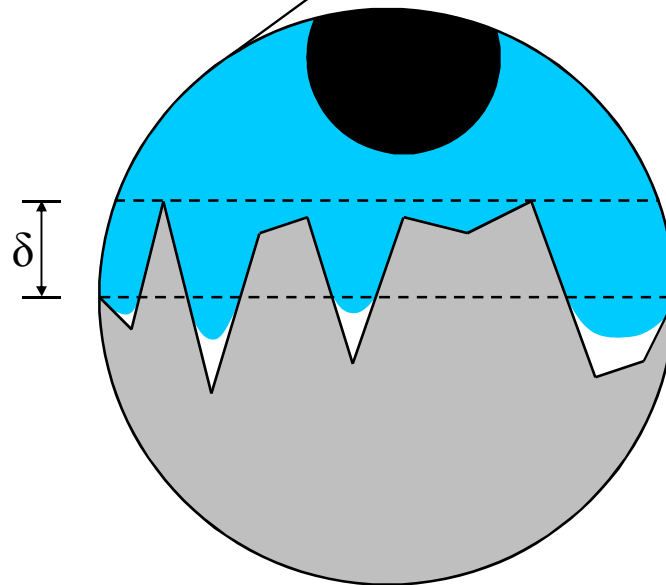
# Material/Processing challenges



**Theoretical reductions in thermal resistance**

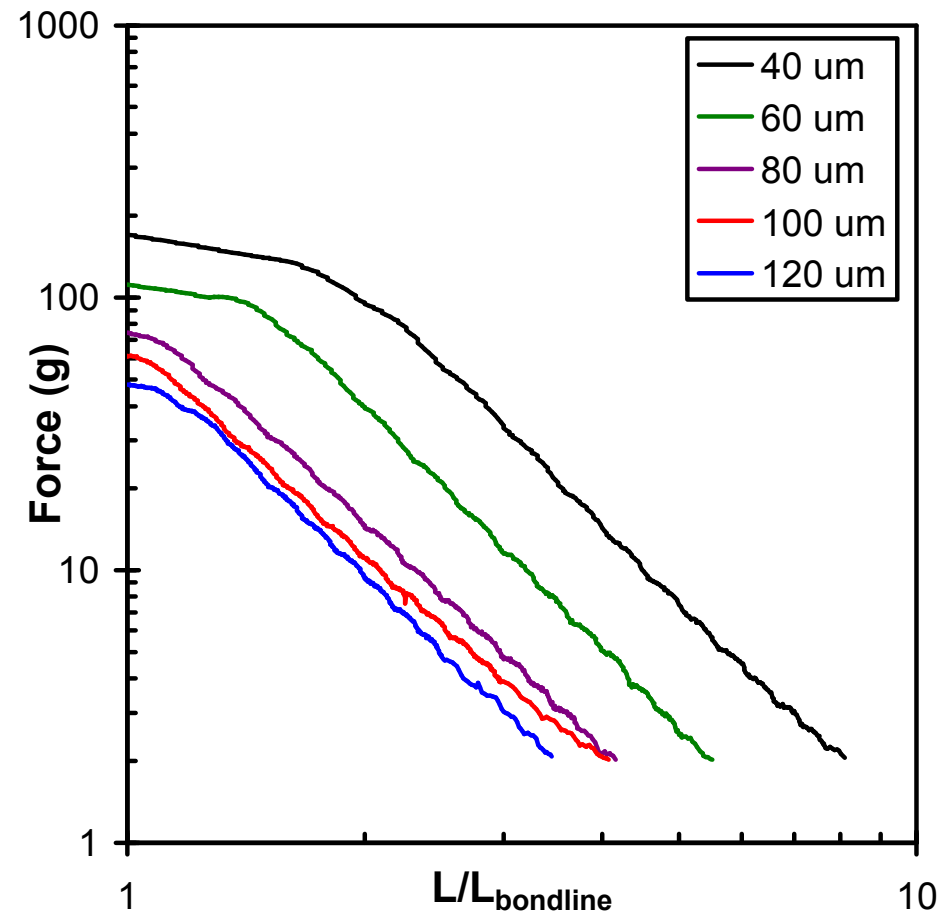
**Increase contact resistance - incomplete wetting of surface**

**Surface layer resistance - filler segregation away from interface**

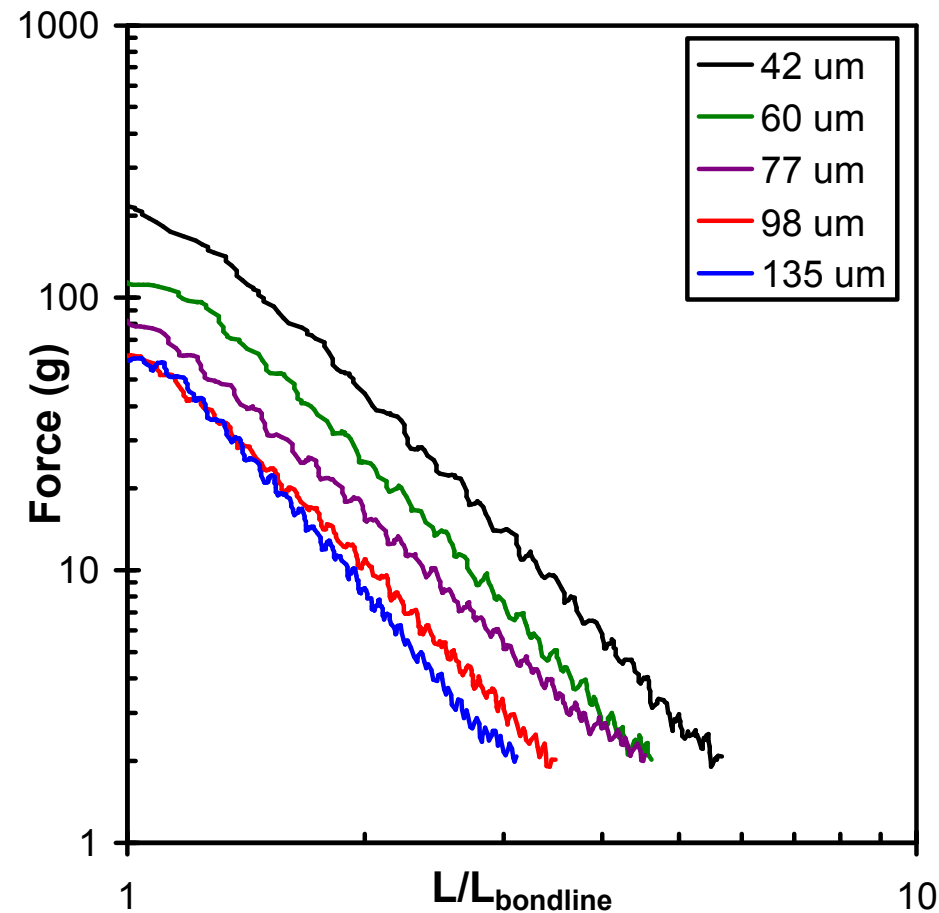


# Squeeze flow data

Epo-tek H20E

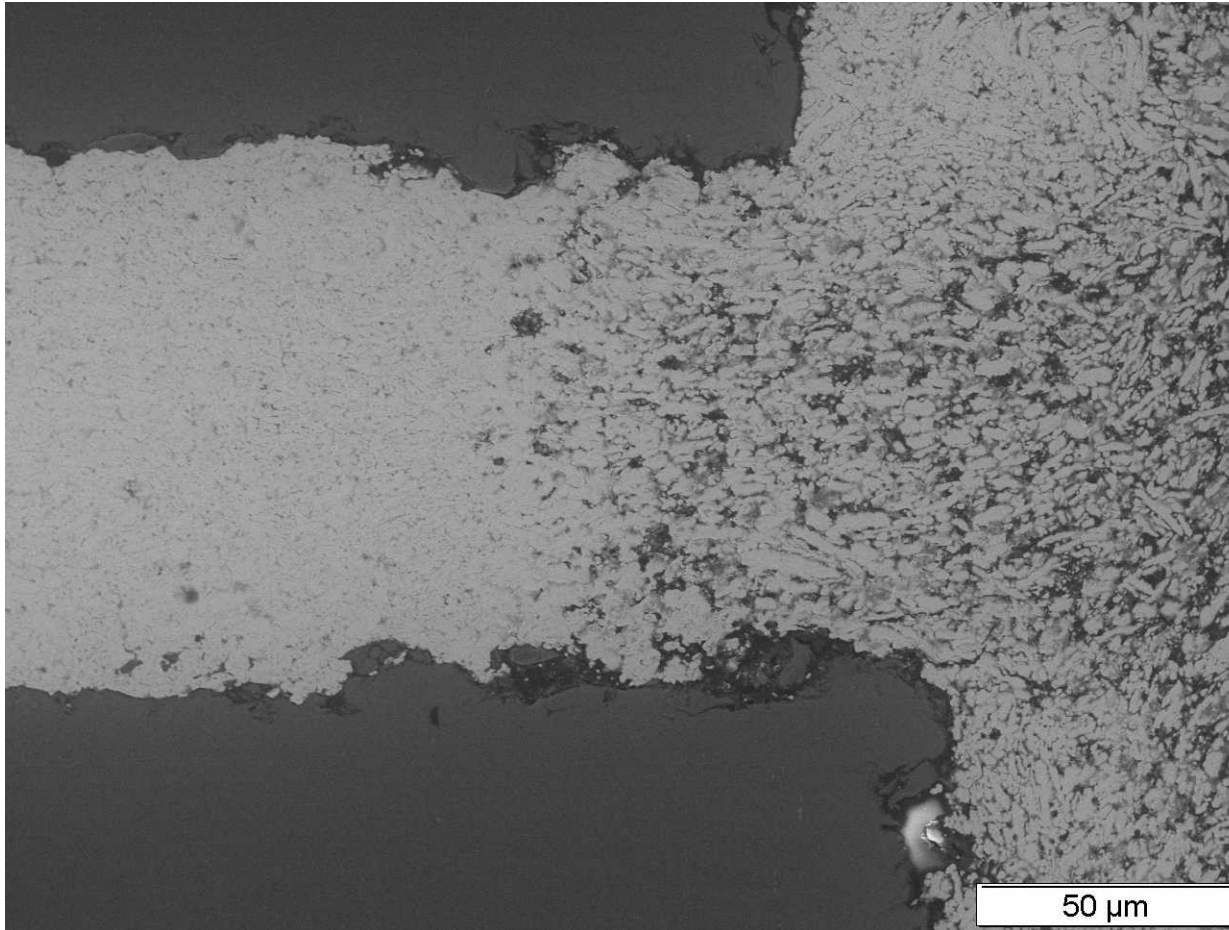


DieMat DM6030Hk



**Larger force for thinner bondlines suggests filler compaction  
Squeeze out of excess material causes slope change at small thickness**

# Controlled squeeze flow

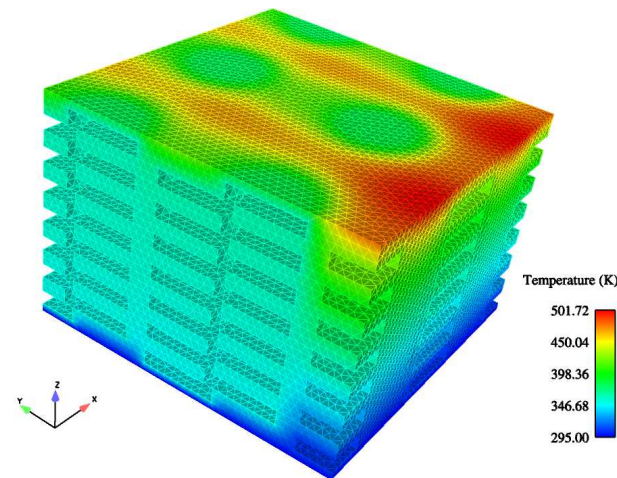
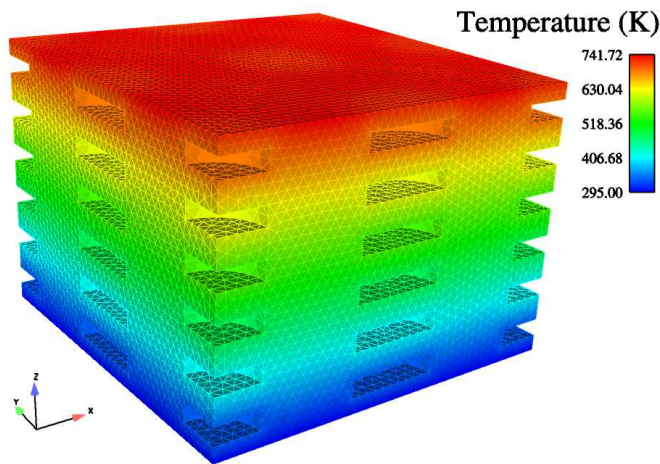


Material - DM6030Hk

**Particles near center are highly compacted,  
squeeze out of epoxy is evident at edge**

# Modeling Heat Conduction in Thermal Interface Materials with Micro-Disks

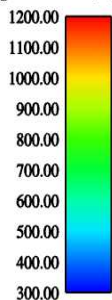
- Perform thermal analysis for TIMs with stacks of micro-disks (20  $\mu\text{m}$  in diameter and 4  $\mu\text{m}$  high; volume fraction = 55%).
- 5 cases studied, w/ interfacial resistance, preliminary results are :  
(matrix:  $k = 0.21 \text{ W/m-K}$ ; filler:  $k = 0.42 \text{ W/m-K}$ )
  - (1) bcc, distributed evenly:  $k = 0.225 \text{ W/m-K}$ ;
  - (2) bcc, closely packed in z-direction:  $k = 0.286 \text{ W/m-K}$ ;
  - (3) shifted bcc, no disk-to-disk contact:  $k = 0.396 \text{ W/m-K}$ ;
  - (4) shifted bcc, some contact:  $k = 0.635 \text{ W/m-K}$ ;
  - (5) stacked & 100% disks contact:  $k = 1.25 \text{ W/m-K}$ .



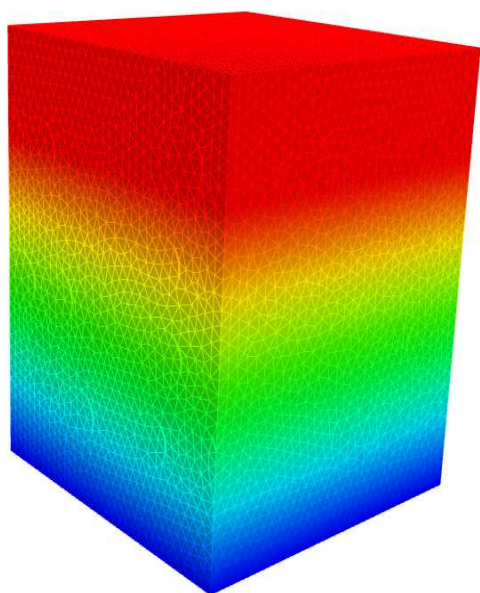


# Preliminary CALORE Analysis of 3 Heterogeneous Interface Materials

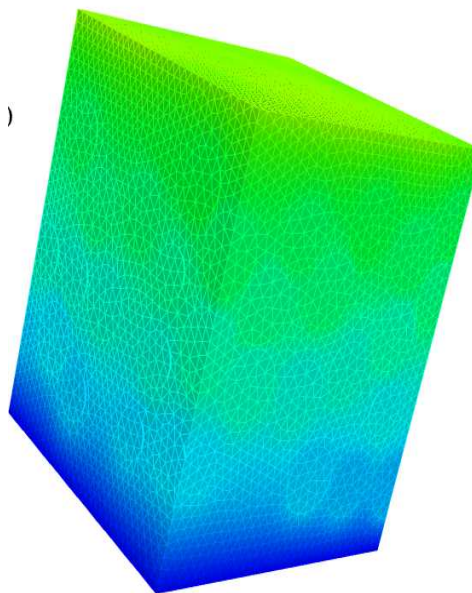
Temperature (K)



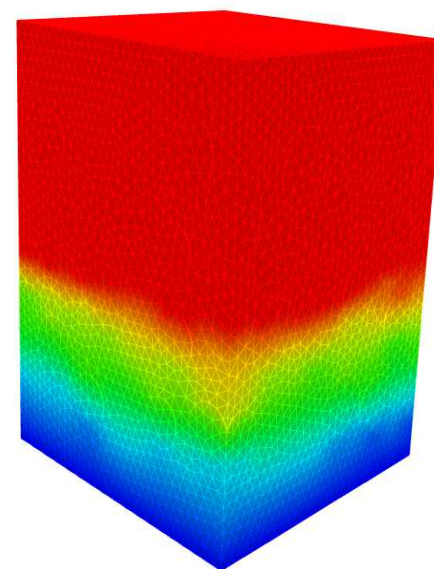
*Polymer only*



*Polymer w/ metal spheres*



*Polymer w/ voids*



	Adhesive Polymer Only	w/ Metal Spheres	w/ voids
Max. T	1491 K	882 K	2124 K
Min. T	295 K	295 K	295 K

# Bulk TIM sample - results

ID	Material	$\rho$	$C_p$	$\alpha$	$\lambda$	$\lambda_{\text{vendor}}$
		(g/cm <sup>3</sup> )	(J/gK)	(cm <sup>2</sup> /s)	(W/mK)	(W/mK)
Epoxy 1	Unfilled epoxy	1.13	1.3	0.0013	0.2	-
TIM 1	Ag-flake filled epoxy 1	3.13	0.51	0.0113	1.8	29
TIM 2	Ag-flake filled epoxy 2	2.84	0.45	0.0830	10.6	17
TIM 3	5% Nanocomposite of TIM 1	2.76	0.61	0.0051	0.6	-

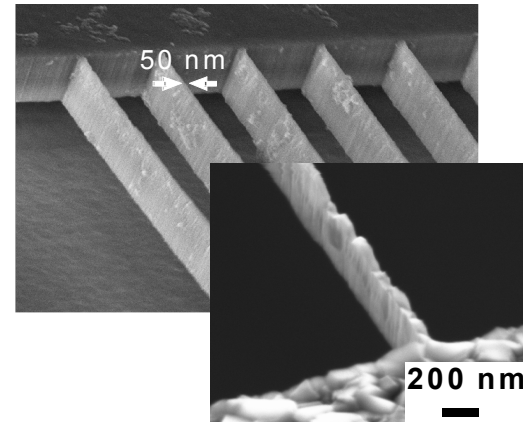
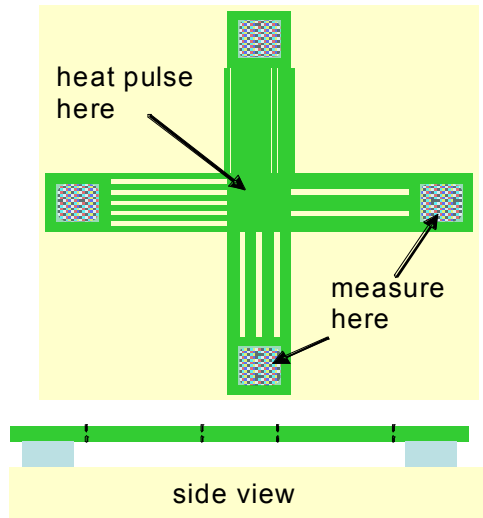
## Preparation:

- 3 samples of each tested, average is shown
- Au/Pd and graphite overcoat layers
- $\lambda$  deviation 10-30%

## Results:

- All filled materials provide improvement over unfilled epoxy
- Both commercial epoxies  $\lambda_{\text{exp}}$  lower than on data sheet  $\lambda_{\text{vendor}}$
- No discernable benefit to addition of 5% nanoparticles for bulk  $\lambda$

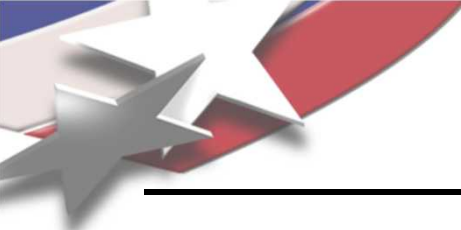
# Experiments with controlled interfaces



**A proposed thermal transport test structure. Legs form bottlenecks with dimensions greater than and less than the phonon mean free path.**

**Lithographically defined structures with dimensions comparable to phonon mean free paths.**





# ***Summary***

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- **Thermal demands are bringing Moore's law to a halt**
- **Heat transfer at the interface plays dominate role**
- **Processing effects**
- **Filler contact resistance**

*Any questions*

